



**MOTOROLA**

**CMOS MSI**

**SYNCHRONOUS PRESETTABLE 4-BIT COUNTERS**

The MC14160B – MC14163B are synchronous programmable counters constructed with complementary MOS P-Channel and N-Channel enhancement mode devices in a single monolithic structure. These counters are functionally equivalent to the 74160–74163 TTL counters.

Two are synchronous programmable BCD counters with asynchronous and synchronous clear inputs respectively (MC14160B, MC14162B). The other two are synchronous programmable 4-bit binary counters with the asynchronous and synchronous clear respectively (MC14161B, MC14163B).

- Internal Look-Ahead for Fast Counting
- Carry Output for N-Bit Cascading
- Synchronously Programmable
- Synchronous Counting
- Load Control Line
- Synchronous or Asynchronous Clear
- Positive Edge Clocked

**MAXIMUM RATINGS\*** (Voltages Referenced to  $V_{SS}$ )

Symbol	Parameter	Value	Unit
$V_{DD}$	DC Supply Voltage	-0.5 to +18.0	V
$V_{in}, V_{out}$	Input or Output Voltage (DC or Transient)	-0.5 to $V_{DD} + 0.5$	V
$i_{in}, i_{out}$	Input or Output Current (DC or Transient), per Pin	$\pm 10$	mA
$P_D$	Power Dissipation, per Package†	500	mW
$T_{stg}$	Storage Temperature	-65 to +150	°C
$T_L$	Lead Temperature (8-Second Soldering)	260	°C

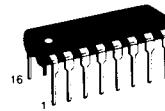
\*Maximum Ratings are those values beyond which damage to the device may occur.  
 †Temperature Derating: Plastic "P and D/DW" Packages: -7.0 mW/°C From 65°C To 125°C  
 Ceramic "L" Packages: -12 mW/°C From 100°C To 125°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range  $V_{SS} \leq (V_{in} \text{ or } V_{out}) \leq V_{DD}$ . Unused inputs must always be tied to an appropriate logic voltage level (e.g., either  $V_{SS}$  or  $V_{DD}$ ). Unused outputs must be left open.

**MC14160B**  
**MC14161B**  
**MC14162B**  
**MC14163B**



**L SUFFIX**  
 CERAMIC  
 CASE 620



**P SUFFIX**  
 PLASTIC  
 CASE 648



**D SUFFIX**  
 SOIC  
 CASE 751B

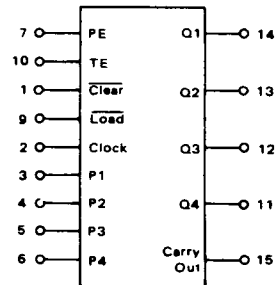
**ORDERING INFORMATION**

MC14XXXBCP Plastic  
 MC14XXXBCL Ceramic  
 MC14XXXBD SOIC

$T_A = -55^\circ\text{C}$  to  $125^\circ\text{C}$  for all packages.

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**BLOCK DIAGRAM**



$V_{DD} = \text{Pin } 16$   
 $V_{SS} = \text{Pin } 8$

# MC14160B thru MC14163B

## ELECTRICAL CHARACTERISTICS (Voltages Referenced to V<sub>SS</sub>)

Characteristic	Symbol	V <sub>DD</sub> Vdc	-55°C		25°C			125°C		Unit
			Min	Max	Min	Typ #	Max	Min	Max	
Output Voltage V <sub>in</sub> = V <sub>DD</sub> or 0	VOL	5.0	—	0.05	—	0	0.05	—	0.05	Vdc
		10	—	0.05	—	0	0.05	—	0.05	
		15	—	0.05	—	0	0.05	—	0.05	
V <sub>in</sub> = 0 or V <sub>DD</sub>	VOH	5.0	4.95	—	4.95	5.0	—	4.95	—	Vdc
		10	9.95	—	9.95	10	—	9.95	—	
		15	14.95	—	14.95	15	—	14.95	—	
Input Voltage (V <sub>O</sub> = 4.5 or 0.5 Vdc) (V <sub>O</sub> = 9.0 or 1.0 Vdc) (V <sub>O</sub> = 13.5 or 1.5 Vdc)	"0" Level V <sub>IL</sub>	5.0	—	1.5	—	2.25	1.5	—	1.5	Vdc
		10	—	3.0	—	4.50	3.0	—	3.0	
		15	—	4.0	—	6.75	4.0	—	4.0	
	"1" Level V <sub>IH</sub>	5.0	3.5	—	3.5	2.75	—	3.5	—	Vdc
		10	7.0	—	7.0	5.50	—	7.0	—	
		15	11	—	11	8.25	—	11	—	
Output Drive Current (V <sub>OH</sub> = 2.5 Vdc) (V <sub>OH</sub> = 4.6 Vdc) (V <sub>OH</sub> = 9.5 Vdc) (V <sub>OH</sub> = 13.5 Vdc)	Source I <sub>OH</sub>	5.0	-3.0	—	-2.4	-4.2	—	-1.7	—	mAdc
		5.0	-0.64	—	-0.51	-0.88	—	-0.36	—	
		10	-1.6	—	-1.3	-2.25	—	-0.9	—	
	Sink I <sub>OL</sub>	5.0	0.64	—	0.51	0.88	—	0.36	—	mAdc
		10	1.6	—	1.3	2.25	—	0.9	—	
		15	4.2	—	3.4	8.8	—	2.4	—	
Input Current	I <sub>in</sub>	15	—	±0.1	—	±0.00001	±0.1	—	±1.0	μAdc
Input Capacitance (V <sub>in</sub> = 0)	C <sub>in</sub>	—	—	—	—	5.0	7.5	—	—	pF
Quiescent Current (Per Package)	I <sub>DD</sub>	5.0	—	5.0	—	0.005	5.0	—	150	μAdc
		10	—	10	—	0.010	10	—	300	
		15	—	20	—	0.015	20	—	600	
Total Supply Current**† (Dynamic plus Quiescent, Per Package) (C <sub>L</sub> = 50 pF on all outputs, all buffers switching)	I <sub>T</sub>	5.0	I <sub>T</sub> = (0.56 μA/kHz) f + I <sub>DD</sub>						μAdc	
		10	I <sub>T</sub> = (1.10 μA/kHz) f + I <sub>DD</sub>							
		15	I <sub>T</sub> = (1.90 μA/kHz) f + I <sub>DD</sub>							

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

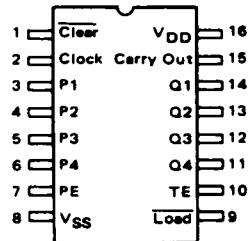
\*\*The formulas given are for the typical characteristics only at 25°C.

†To calculate total supply current at loads other than 50 pF:

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) V/k$$

where: I<sub>T</sub> is in μA (per package), C<sub>L</sub> in pF, V = (V<sub>DD</sub> - V<sub>SS</sub>) in volts, f in kHz is input frequency, and k = 0.001.

### PIN ASSIGNMENT



# MC14160B thru MC14163B

## SWITCHING CHARACTERISTICS (C<sub>L</sub> = 50 pF, T<sub>A</sub> = 25°C)

Characteristic	Symbol	V <sub>DD</sub> V <sub>dc</sub>	Min	Typ #	Max	Unit				
Output Rise Time	t <sub>TLH</sub>	5.0	—	100	200	ns				
		10	—	50	100					
		15	—	40	80					
Output Fall Time	t <sub>THL</sub>	5.0	—	100	200	ns				
		10	—	50	100					
		15	—	40	80					
Propagation Delay Time	t <sub>PLH</sub> , t <sub>PHL</sub>					ns				
		Clock to Q								
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.90 ns/pF) C <sub>L</sub> + 305 ns	5.0	—	350		700			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.36 ns/pF) C <sub>L</sub> + 132 ns	10	—	150		300			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.26 ns/pF) C <sub>L</sub> + 87 ns	15	—	100		200			
		Clock to Carry Out								
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.90 ns/pF) C <sub>L</sub> + 395 ns	5.0	—	440		880			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.36 ns/pF) C <sub>L</sub> + 167 ns	10	—	185		370			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.26 ns/pF) C <sub>L</sub> + 112 ns	15	—	125		250			
		TE to Carry Out								
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.90 ns/pF) C <sub>L</sub> + 225 ns	5.0	—	300		600			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.36 ns/pF) C <sub>L</sub> + 112 ns	10	—	130		260			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.26 ns/pF) C <sub>L</sub> + 77 ns	15	—	90		180			
		Clear to Q (MC14160B, MC14161B only)								
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.90 ns/pF) C <sub>L</sub> + 110 ns	5.0	—	350		700			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.36 ns/pF) C <sub>L</sub> + 37 ns	10	—	150		300			
		t <sub>PLH</sub> , t <sub>PHL</sub> = (0.26 ns/pF) C <sub>L</sub> + 22 ns	15	—	100		200			
		Setup Times	t <sub>su</sub>						ns	
				Data to Clock						
				5.0	320		160	—		
10	130			65	—					
15	90			45	—					
Load to Clock										
5.0	600			300	—					
10	260			130	—					
15	180			90	—					
Enable to Clock (PE or TE)										
5.0	420			210	—					
10	170			85	—					
15	120	60	—							
Clear to Clock (MC14162B, MC14163B only)										
5.0	310	155	—							
10	110	55	—							
15	70	35	—							
Hold Times	t <sub>h</sub>					ns				
		Clock to Data								
		5.0	-10	-80	—					
		10	-5	-25	—					
		15	0	-15	—					
		Clock to Load								
		5.0	-40	-195	—					
		10	-10	-80	—					
		15	-5	-50	—					
		Clock to PE								
		5.0	-40	-175	—					
		10	-10	-70	—					
		15	0	-40	—					
		Clock to TE								
		5.0	-150	-280	—					
		10	-30	-130	—					
		15	-20	-80	—					
		Clock to Clear (MC14162B, MC14163B only)								
5.0	80	40	—							
10	30	15	—							
15	-10	-70	—							
Clear Removal Time (MC14160B, MC14161B only)	t <sub>rem</sub>	5.0	90	30	—	ns				
		10	65	20	—					
		15	55	20	—					

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# MC14160B thru MC14163B

## SWITCHING CHARACTERISTICS ( $C_L = 50$ pF, $T_A = 25^\circ\text{C}$ ) (Continued)

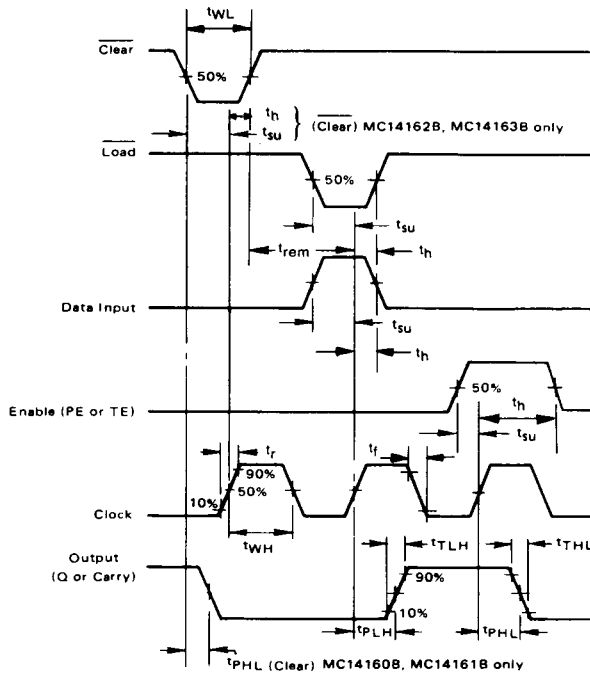
Characteristic	Symbol	$V_{DD}$ Vdc	Min	Typ #	Max	Unit
Clear Pulse Width, Low (MC14160B, MC14161B only)	$t_{WL}$	5.0	200	100	—	ns
		10	90	45	—	
		15	60	30	—	
Clock Pulse Width, High	$t_{WH}$	5.0	250	125	—	ns
		10	100	50	—	
		15	70	35	—	
Clock Rise and Fall Time	$t_r$ $t_f$	5	—	—	15	$\mu\text{s}$
		10	—	—	5	
		15	—	—	4	
Clock Pulse Frequency	$f_{cl}$	5.0	—	2.0	1.0	MHz
		10	—	5.0	2.5	
		15	—	8.0	4.0	

\*The formulas given are for the typical characteristics only at 25°C.

#Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

# MC14160B thru MC14163B

## SWITCHING WAVEFORMS



## FUNCTIONAL DESCRIPTION

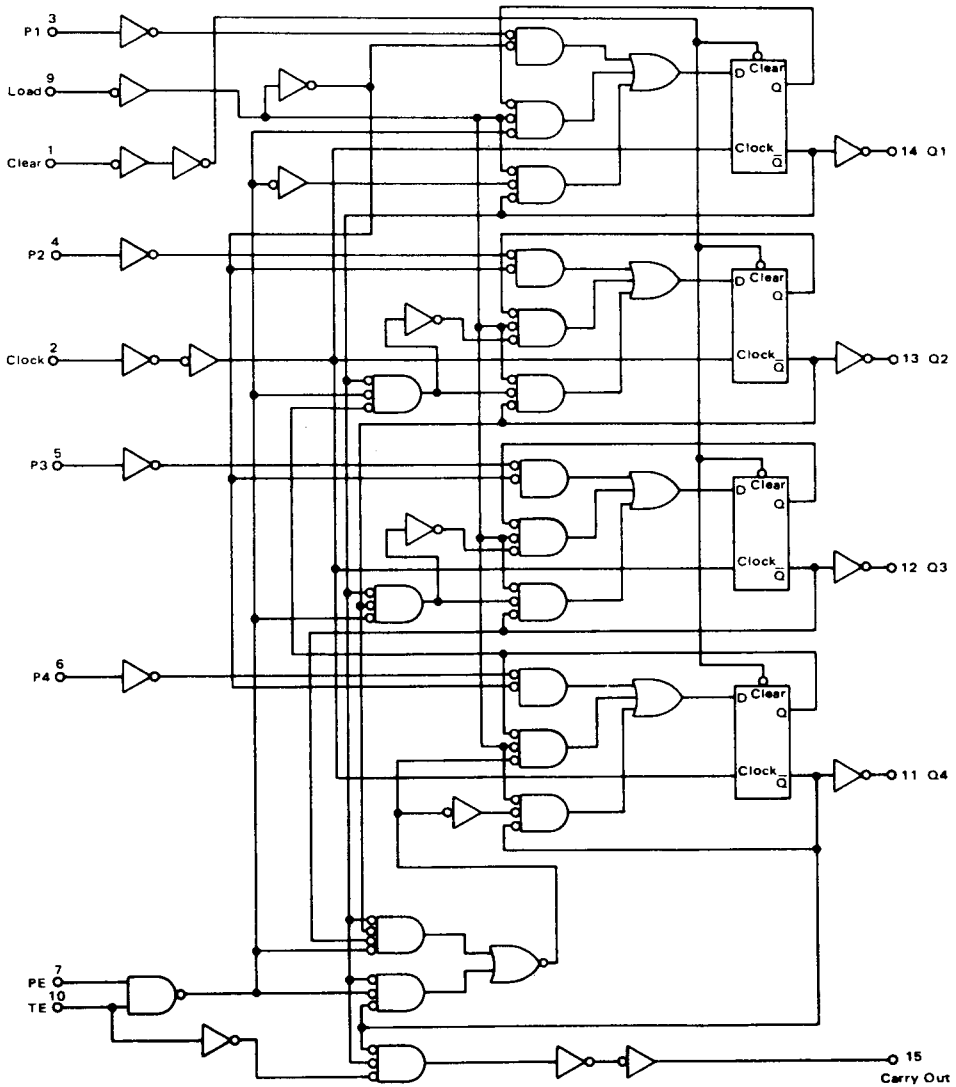
These counters are fully programmable; that is the outputs may be preset to either level. As presetting is synchronous, setting up a low level at the load input disables the counter and causes the outputs to agree with the setup data after the next clock pulse regardless of the levels of the enable inputs. The clear function for the MC14160B, MC14161B is asynchronous and a low level at the clear input sets all four of the flip-flop outputs low regardless of the levels of the clock, load or enable inputs. The clear function for the MC14162B and MC14163B is synchronous and a low level at the clear inputs sets all four of the flip-flop outputs low after the next clock pulse, regardless of the levels of the enable inputs. This synchronous clear allows the count length to be modified easily; decoding the maximum count de-

sired can be accomplished with one external NAND gate. The gate output is connected to the clear input to synchronously clear the counter to 0000 (LLLL).

The carry look-ahead circuitry provides for cascading counters for n-bit synchronous applications without additional gating. Instrumental in accomplishing this function are two count-enable inputs and a carry output. Both count-enable inputs (PE, TE) must be high to count, and enable input TE fed forward to enable the carry output. The carry output thus enabled will produce a positive output pulse with a duration approximately equal to the positive portion of the Q1 output. This positive overflow carry pulse can be used to enable successive cascaded stages.

# MC14160B thru MC14163B

MC14160B, MC14162B LOGIC DIAGRAM  
(Clear is synchronous for MC14162B)



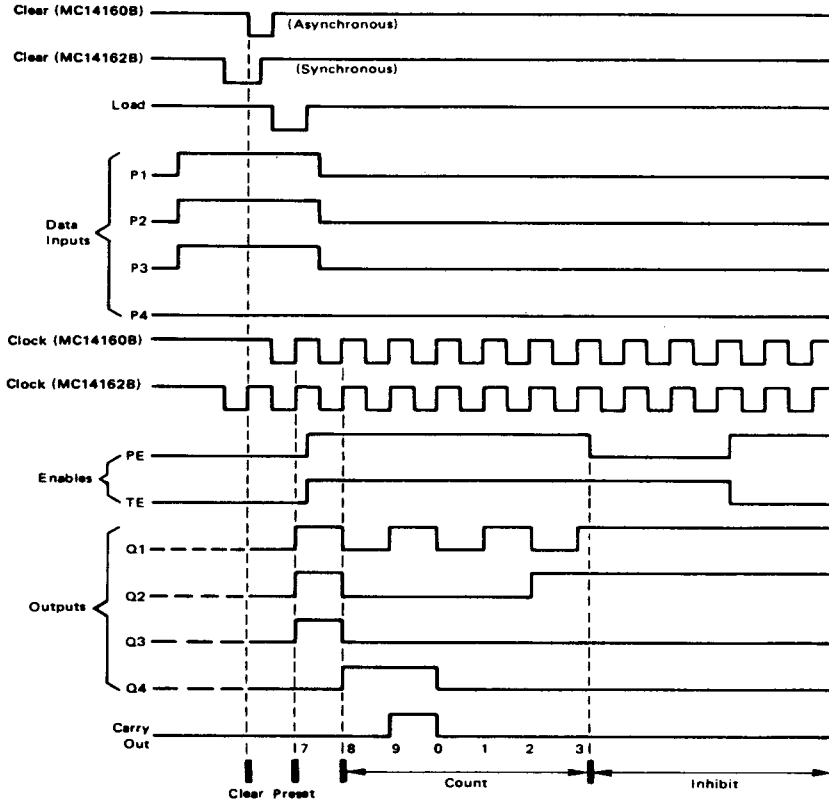
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# MC14160B thru MC14163B

## MC14160B, MC14162B TIMING DIAGRAM

Sequence illustrated in waveforms:

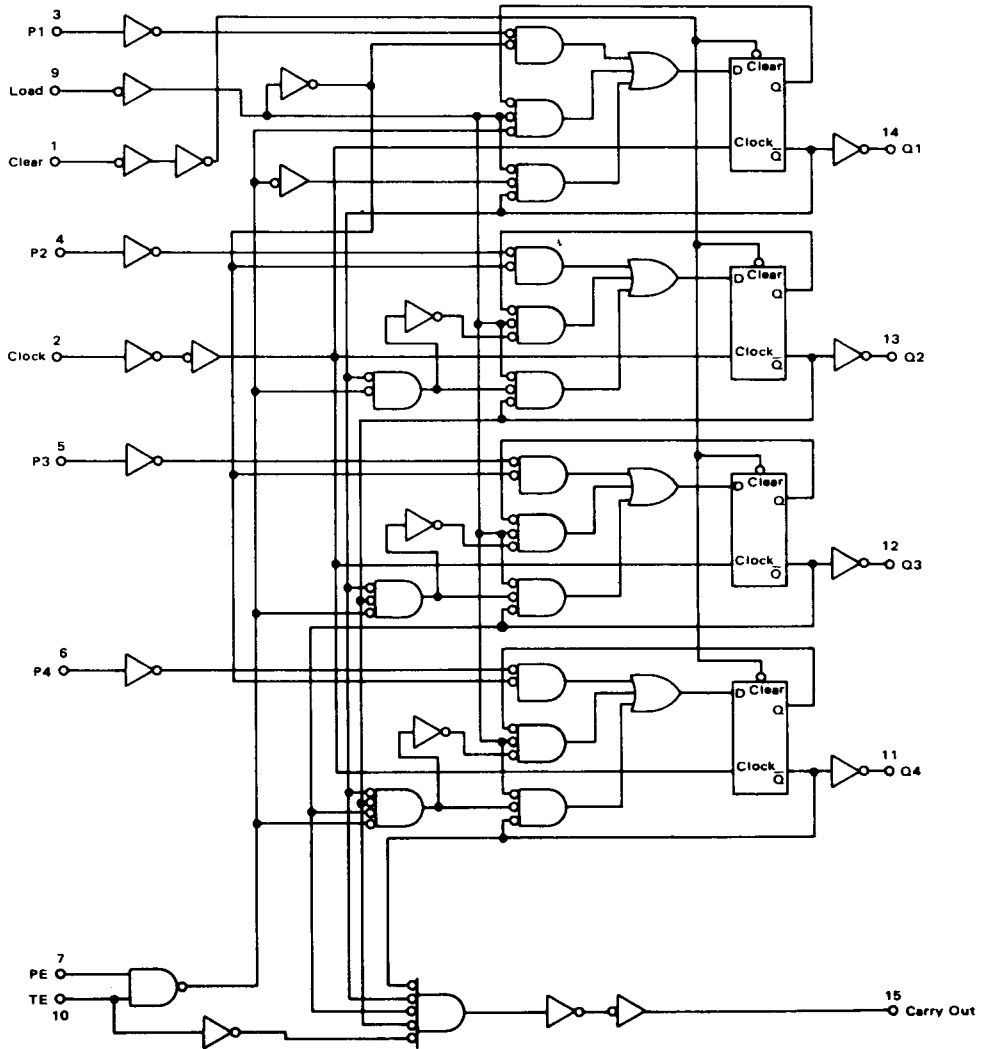
1. Clear outputs to zero.
2. Preset to BCD seven.
3. Count to eight, nine, zero, one, two, and three.
4. Inhibit



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# MC14160B thru MC14163B

MC14161B, MC14163B LOGIC DIAGRAM  
(Clear is Synchronous for MC14163B)



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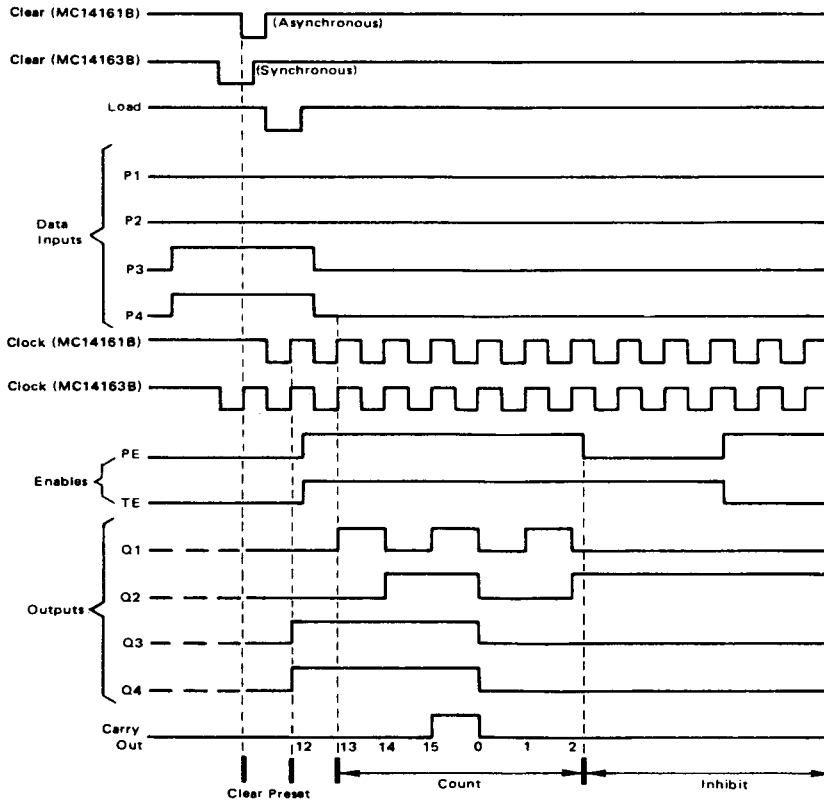


# MC14160B thru MC14163B

## MC14161B, MC14163B TIMING DIAGRAM

Sequence illustrated in waveforms:

1. Clear outputs to zero.
2. Preset to binary twelve.
3. Count to thirteen, fourteen, fifteen, zero, one, and two.
4. Inhibit



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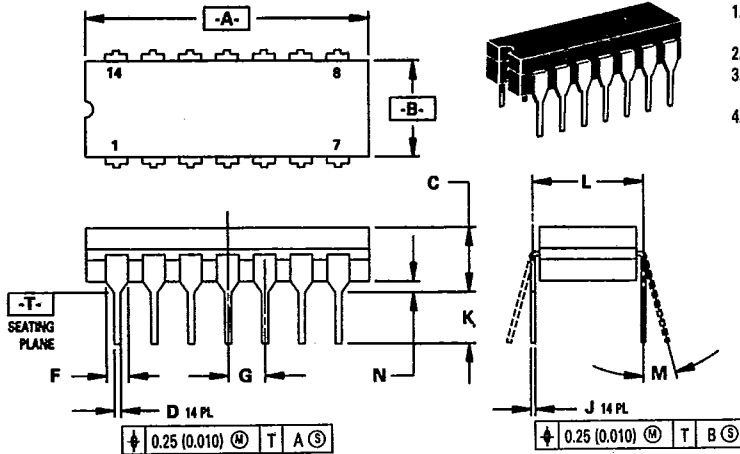
# PACKAGE DIMENSIONS

T-90-20

The standard package availability for each device is indicated on the front page of the individual data sheets. Dimensions for the packages are given in this chapter. Surface mount packages may be special ordered by specifying the following suffixes: "D" (narrow SOIC), "DW" (wide SOIC), or "FN" (PLCC). For example, to order a quad NOR gate, use MC14001BD.

## 14-PIN PACKAGE

### CERAMIC PACKAGE CASE 632-08

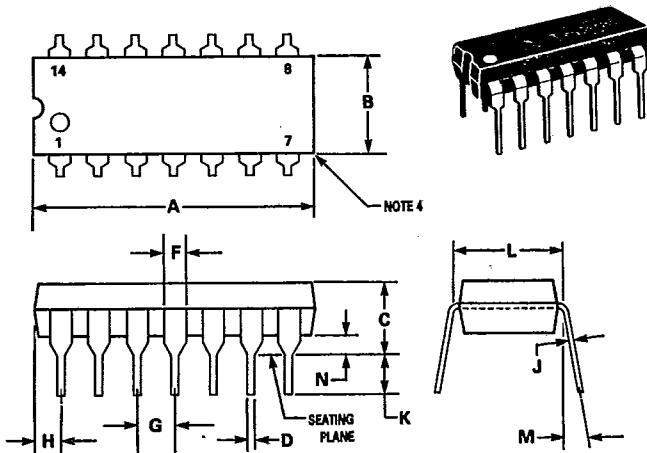


**NOTES:**

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIM F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	19.05	19.94	0.750	0.785
B	6.23	7.11	0.245	0.280
C	3.94	5.08	0.155	0.200
D	0.39	0.50	0.015	0.020
F	1.40	1.65	0.055	0.065
G	2.54 BSC		0.100 BSC	
J	0.21	0.38	0.008	0.015
K	3.18	4.31	0.125	0.170
L	7.62 BSC		0.300 BSC	
M	0°	15°	0°	15°
N	0.51	1.01	0.020	0.040

### PLASTIC PACKAGE CASE 646-06



**NOTES:**

1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
2. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
4. ROUNDED CORNERS OPTIONAL.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	18.16	19.56	0.715	0.770
B	6.10	6.60	0.240	0.260
C	3.69	4.69	0.145	0.185
D	0.38	0.53	0.015	0.021
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	1.32	2.41	0.052	0.095
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	0°	10°	0°	10°
N	0.39	1.01	0.015	0.039

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PACKAGE DIMENSIONS (Continued)

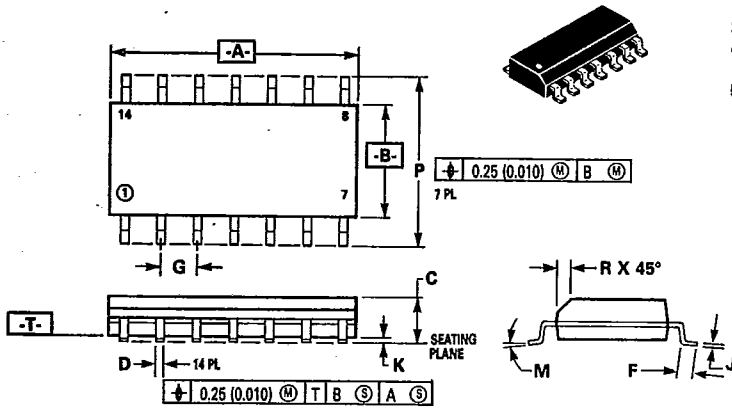
14-PIN PACKAGE

SOIC PACKAGE  
CASE 751A-02  
D SUFFIX

NOTES:

1. DIMENSIONS A AND B ARE DATUMS AND T IS A DATUM SURFACE.
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
3. CONTROLLING DIMENSION: MILLIMETER.
4. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
5. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

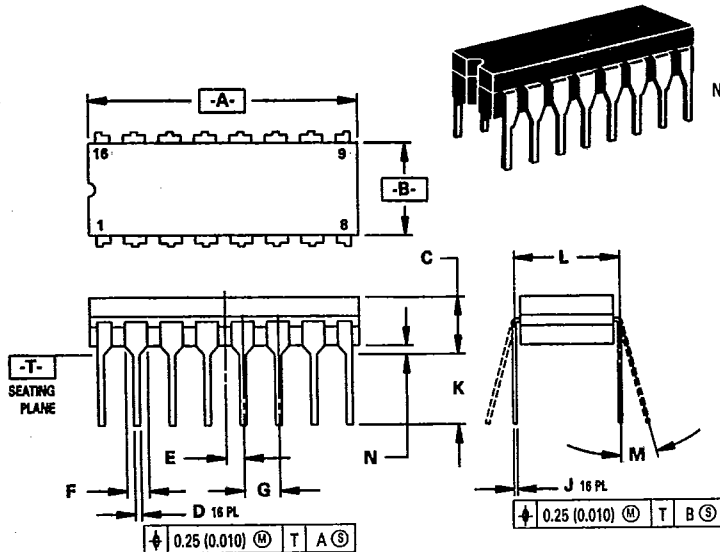
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019



PACKAGE DIMENSIONS (Continued)

16-PIN PACKAGE

CERAMIC PACKAGE  
CASE 620-09

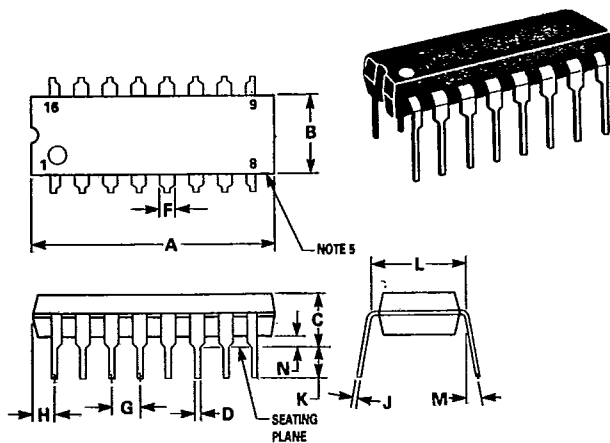


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIM F MAY NARROW TO 0.76 (0.030) WHERE THE LEAD ENTERS THE CERAMIC BODY.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	19.05	19.55	0.750	0.770
B	6.10	7.36	0.240	0.290
C	—	4.19	—	0.165
D	0.39	0.53	0.015	0.021
E	1.27 BSC		0.050 BSC	
F	1.40	1.77	0.055	0.070
G	2.54 BSC		0.100 BSC	
J	0.23	0.27	0.009	0.011
K	—	5.08	—	0.200
L	7.62 BSC		0.300 BSC	
M	0°	15°	0°	15°
N	0.39	0.88	0.015	0.035

PLASTIC PACKAGE  
CASE 648-06



NOTES:

1. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION.
2. DIMENSION "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION "B" DOES NOT INCLUDE MOLD FLASH.
4. "F" DIMENSION IS FOR FULL LEADS.
5. ROUNDED CORNERS OPTIONAL.

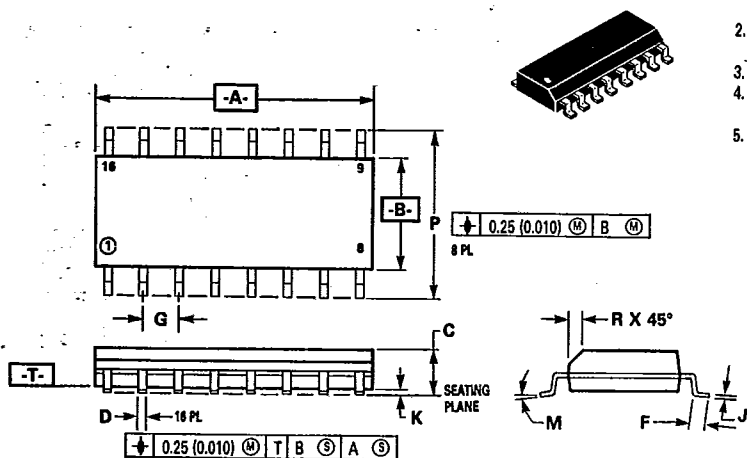
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	18.80	21.34	0.740	0.840
B	6.10	6.60	0.240	0.260
C	3.69	4.69	0.145	0.185
D	0.38	0.53	0.015	0.021
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.38	2.41	0.015	0.095
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	0°	10°	0°	10°
N	0.39	1.01	0.015	0.040

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PACKAGE DIMENSIONS (Continued)

16-PIN PACKAGE

SOIC PACKAGE  
CASE 751B-03  
D SUFFIX

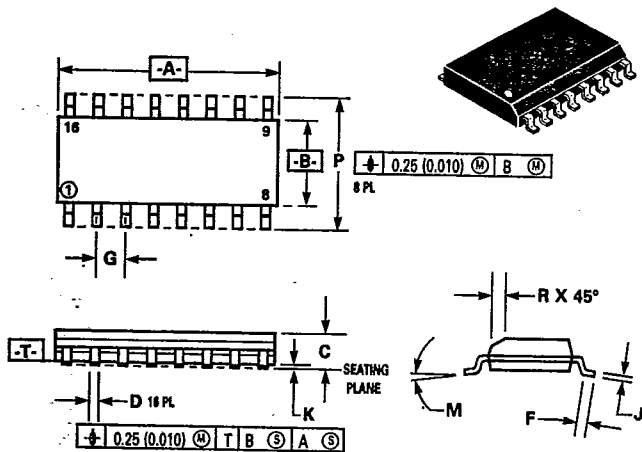


NOTES:

1. DIMENSIONS A AND B ARE DATUMS AND T IS A DATUM SURFACE.
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
3. CONTROLLING DIMENSION: MILLIMETER.
4. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
5. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.80	10.00	0.386	0.393
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

SOIC PACKAGE  
CASE 751G-01  
DW SUFFIX



NOTES:

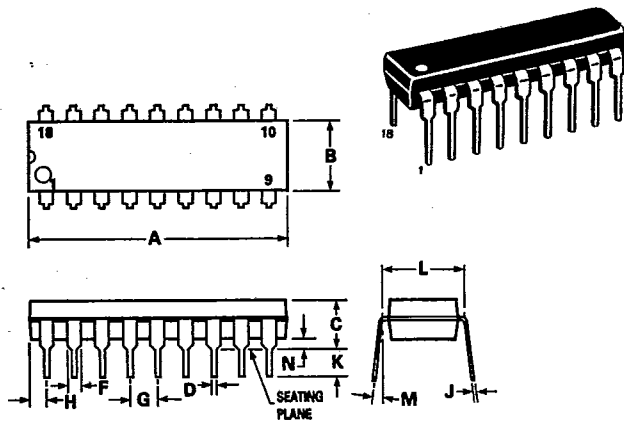
1. DIMENSIONS A AND B ARE DATUMS AND T IS A DATUM SURFACE.
2. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
3. CONTROLLING DIMENSION: MILLIMETER.
4. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
5. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	10.15	10.45	0.400	0.411
B	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27 BSC		0.050 BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	10.05	10.55	0.395	0.415
	0.25	0.75	0.010	0.029

PACKAGE DIMENSIONS (Continued)

18-PIN PACKAGE

PLASTIC PACKAGE  
CASE 707-02

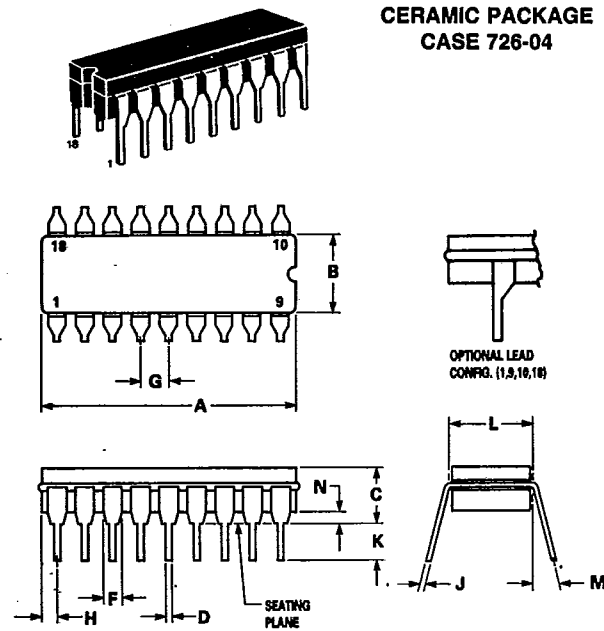


NOTES:

1. POSITIONAL TOLERANCE OF LEADS (D), SHALL BE WITHIN 0.25mm(0.010) AT MAXIMUM MATERIAL CONDITION, IN RELATION TO SEATING PLANE AND EACH OTHER.
2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	22.22	23.24	0.875	0.915
B	6.10	6.60	0.240	0.260
C	3.56	4.57	0.140	0.180
D	0.36	0.56	0.014	0.022
F	1.27	1.78	0.050	0.070
G	2.54 BSC		0.100 BSC	
H	1.02	1.52	0.040	0.060
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	0°	15°	0°	15°
N	0.51	1.02	0.020	0.040

CERAMIC PACKAGE  
CASE 726-04



NOTES:

1. LEADS, TRUE POSITIONED WITHIN 0.25 mm (0.010) DIA. AT SEATING PLANE, AT MAXIMUM MATERIAL CONDITION.
2. DIM "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIM "A" & "B" INCLUDES MENISCUS.
4. "E" DIMENSION IS FOR FULL LEADS. "HALF" LEADS ARE OPTIONAL AT LEAD POSITIONS 1, 9, 10, AND 18.

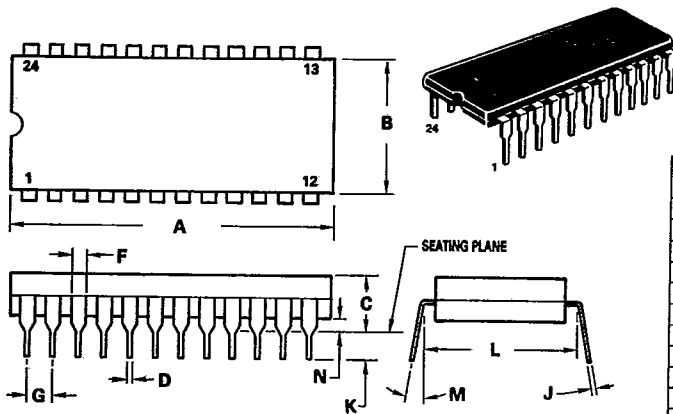
DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	22.35	23.11	0.880	0.910
B	6.10	7.49	0.240	0.295
C	—	5.08	—	0.200
D	0.38	0.53	0.015	0.021
F	1.40	1.78	0.055	0.070
G	2.54 BSC		0.100 BSC	
H	0.51	1.14	0.020	0.045
J	0.20	0.30	0.008	0.012
K	3.18	4.32	0.125	0.170
L	7.62 BSC		0.300 BSC	
M	0°	15°	0°	15°
N	0.51	1.02	0.020	0.040

9

PACKAGE DIMENSIONS (Continued)

24-PIN PACKAGE

CERAMIC PACKAGE  
CASE 623-05

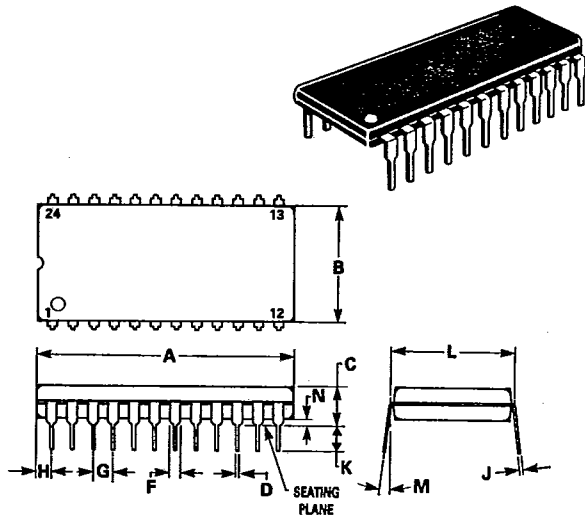


NOTES:

1. DIM "L" TO CENTER OF LEADS WHEN FORMED PARALLEL.
2. LEADS WITHIN 0.13 mm (0.005) RADIUS OF TRUE POSITION AT SEATING PLANE AT MAXIMUM MATERIAL CONDITION. (WHEN FORMED PARALLEL).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	31.24	32.77	1.230	1.290
B	12.70	15.49	0.500	0.610
C	4.06	5.59	0.160	0.220
D	0.41	0.51	0.016	0.020
F	1.27	1.52	0.050	0.060
G	2.54 BSC		0.100 BSC	
J	0.20	0.30	0.008	0.012
K	3.18	4.06	0.125	0.160
L	15.24 BSC		0.600 BSC	
M	0° 15°		0° 15°	
N	0.51	1.27	0.020	0.050

PLASTIC PACKAGE  
CASE 709-02



NOTES:

1. POSITIONAL TOLERANCE OF LEADS (D), SHALL BE WITHIN 0.25 mm (0.010) AT MAXIMUM MATERIAL CONDITION, IN RELATION TO SEATING PLANE AND EACH OTHER.
2. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
3. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	31.37	32.13	1.235	1.265
B	13.72	14.22	0.540	0.560
C	3.94	5.08	0.155	0.200
D	0.36	0.56	0.014	0.022
F	1.02	1.52	0.040	0.060
G	2.54 BSC		0.100 BSC	
H	1.65	2.03	0.065	0.080
J	0.20	0.38	0.008	0.015
K	2.92	3.43	0.115	0.135
L	15.24 BSC		0.600 BSC	
M	0° 15°		0° 15°	
N	0.51	1.02	0.020	0.040